#### **PRODUCT / PROCESS CHANGE NOTIFICATION**

1. PCN basic data		
1.1 Company		STMicroelectronics International N.V
1.2 PCN No.		AMS/21/12543
1.3 Title of PCN		Qualification of subcontractor TSHT for selected products in S016 package
1.4 Product Category		See product list
1.5 Issue date		2021-01-29

2. PCN Team		
2.1 Contact supplier		
2.1.1 Name	HARTMANN DORIS	
2.1.2 Phone	+49 89460062186	
2.1.3 Email	doris.hartmann@st.com	
2.2 Change responsibility		
2.2.1 Product Manager	Marcello SAN BIAGIO	
2.1.2 Marketing Manager	Salvatore DI VINCENZO	
2.1.3 Quality Manager	Giuseppe LISI	

3. Change		
3.1 Category	3.2 Type of change	3.3 Manufacturing Location
	Line transfer for a full process or process brick (process step, control plan, recipes) from one site to another site: Assembly site (SOP 2617)	TSHT

4. Description of change		
	Old	New
4.1 Description	Assembly plant : - Amkor - ASE - ST Shenzhen	Assembly plant : - ST Shenzhen - TSHT
4.2 Anticipated Impact on form,fit, function, quality, reliability or processability?	No impact	

5. Reason / motivation for change		
	The qualification of TSHT for SO16 package will allow us to rationalize our production tool and provide better delivery service	
5.2 Customer Benefit	SERVICE IMPROVEMENT	

6. Marking of parts / traceability of change		
6.1 Description	New finished good codes	

7. Timing / schedule		
7.1 Date of qualification results	2021-01-08	
7.2 Intended start of delivery	2021-04-30	
7.3 Qualification sample available?	Upon Request	

8. Qualification / Validation				
8.1 Description 12543 W1410-2021-6088-New Assembly Plant TSHT for SO 16 Narrow_ ULN2003D1R (L203).pdf				
8.2 Qualification report and qualification results	Available (see attachment)	Issue Date	2021-01-29	

#### 9. Attachments (additional documentations)

12543 Public product.pdf 12543 W1410-2021-6088-New Assembly Plant TSHT for SO 16 Narrow\_ ULN2003D1R (L203).pdf

10. Affected parts			
10. 1 Current		10.2 New (if applicable)	
10.1.1 Customer Part No	10.1.2 Supplier Part No	10.1.2 Supplier Part No	
	ULN2001D1013TR		
	ULN2002D1013TR		
	ULN2003D1013TR		
	ULN2004D1013TR		

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AMS (Analog, MEMS & Sensor Group)

General Purpose Analog & RF Division

Power Management

REL.6088- 1410 -2021

Quality and Reliability

# **Reliability Evaluation Report**

New Assembly Plant

SC-Tianshui Huatian-China (TSHT) SO 16 Narrow

# TV: ULN2003D1R (L203)

General Ir	formation	Locations		
Product Lines	L20303	Wafer fab	Singapore 6	
Product Description	DARLINGTON ARRAY			
P/N	ULN2003D1R	Assembly plant	SC-Tianshui Huatian-China (TSHT)	
Product Group	AMS (Analog MEMS & Sensor Group)			
Product division	General Purpose Analog & RF Division POWER MANAGEMENT	Reliability Trials	PASS	
Package Silicon Process technology	SO 16 Narrow Bipolar			

Version	Date	Pages	Created by	Approved by	Comment
1.0	January 2021	6	Antonio Russo	Giuseppe Lisi	Final Report

### General Purpose Analog & RF Division

Power Management

### Quality and Reliability

# TABLE OF CONTENTS

1	APPLICABLE AND REFERENCE DOCUMENTS	.3
2	RELIABILITY EVALUATION OVERVIEW	.3
2.	1 OBJECTIVES	.3
2.	1 CONCLUSION	.3
3	CHANGE DESCRIPTION	4
4	CONSTRUCTION NOTE	.4
5	TESTS RESULTS SUMMARY	. <b>5</b>
	5.2 TEST PLAN AND RESULTS SUMMARY	.5
6	ANNEXES	.5
	ANNEXES	.5
	PLEASE REFER TO PRODUCT DATASHEET	.5
	6.2 PACKAGE MECHANICAL DATA	.5
7	TEST DESCRIPTION	6

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REL.6088- 1410 -2021

Quality and Reliability

# 1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference	Short description		
JESD47	Stress-Test-Driven Qualification of Integrated Circuits		

# 2 RELIABILITY EVALUATION OVERVIEW

## 2.1 OBJECTIVES

This report contains the reliability evaluation of ULN2003D1R (L203) SO 16 narrow in the new assembly plant SC-Tianshui Huatian-China (TSHT). The reliability evaluation has been performed on three different assy lots as requested by JEDEC JESD47 for this type of change (new assembly plant).

### 2.1 CONCLUSION

Qualification Plan requirements have been defined accordingly to JESD47. We have completed the reliability trials on all 3 assy lots and have shown that the devices behave correctly against environmental tests (no failure). Moreover, the stability of electrical parameters during the accelerated tests demonstrates the ruggedness of the products and safe operation, which is consequently expected during their lifetime. More details are available below in test and results summary.

AMS (Analog, MEMS & Sensor Group)

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Quality and Reliability

# 3 CHANGE DESCRIPTION

Qualification of new Assembly Plant SC-Tianshui Huatian-China (TSHT) for SO 16 Narrow

# 4 CONSTRUCTION NOTE

. [	L203		
Wafer/Die fab. Information			
Wafer fab manufacturing location	Singapore 6		
Technology	Bipolar		
Die finishing back side	Cr/Ni/Ag		
Die size	2280 x 1200 um		
Passivation type	SiN (nitride)		
Assembly information			
Assembly site	SC-Tianshui Huatian-China (TSHT)		
Package description	SO 16 Narrow		
Mold Compound	Ероху		
Frame	Pure Tin Plating Sn 100%		
Bond Wire	1.0 mil PdCu		

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# 5 TESTS RESULTS SUMMARY

# 5.1 Test vehicle

Lot #	Commercial product	Rawline	Package	Product Line	
1					
2	ULN2003D1R	PRQ7*L2034A6	SO 16	L20303	
3					

# 5.2 Test plan and results summary

Test	PC Std ref.	Std ref.	Conditions	ss Steps -	Stope		SS				
Test	FU	Stu lei.	Conditions		Lot 1	Lot 2	Lot 3	Note			
Die Oriented	Reliat	oility trials		-		-					
		150,000			168 H	0/80	0/80	0/80			
	JESD22 A-103	Ta = 150°C	240	500 H	0/80	0/80	0/80	2			
		A-105			1000 H	0/80	0/80	0/80			
Package Orio	ented I	Reliability trials									
PC	-	JESD22 A-113	Drying 24 H @ 125°C Store 168 H @ Ta=85°C Rh=85% Oven Reflow @ Tpeak=260°C 3 times	480	Final	Pass	Pass	Pass			
AC	Y	JESD22 A-102	Pa=2Atm / Ta=121°C	240	96 H	0/80	0/80	0/80	1		
тс ү	JESD22	2 Ta = -65°C to 150°C	240	100cy	0/80	0/80	0/80	1			
10	I	A-104	$1a = -65^{\circ}C$ to $150^{\circ}C$		$1a = -65^{\circ}C (0, 150^{\circ}C)$	240	500 cy	0/80	0/80	0/80	I
Package Ass	embly	Integrity trials									
WBP	-	M2011	30 wires, characterization	15	Final	Pass CPK>1.66	Pass CPK>1.66	Pass CPK>1.66			
WBS	-	JESD22-B116	30 balls, characterization	15	Final	Pass CPK>1.66	Pass CPK>1.66	Pass CPK>1.66			
Solderability	-	JESD22-B102	>95% lead coverage	15	Final	Pass	Pass	Pass			

1. Preconditioning with soak per J-STD-020 at rated moisture sensitivity level prior to acceleration stress testing

2. Preconditioning without soak

# 6 ANNEXES

# 6.1 Pin connections

Please refer to product datasheet

# 6.2 Package Mechanical data

Please refer to product datasheet

### AMS (Analog, MEMS & Sensor Group)

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### Quality and Reliability

# 7 TEST DESCRIPTION

Test name	Description	Purpose
Die Oriented		
<b>HTSL</b> High Temperature Storage Life	The device is stored in unbiased condition at the max. temperature allowed by the package materials, sometimes higher than the max. operative temperature.	To investigate the failure mechanisms activated by high temperature, typically wire-bonds solder joint ageing, data retention faults, metal stress- voiding.
Package Oriented		
<b>PC</b> Preconditioning	The device is submitted to a typical temperature profile used for surface mounting devices, after a controlled moisture absorption.	As stand-alone test: to investigate the moisture sensitivity level. As preconditioning before other reliability tests: to verify that the surface mounting stress does not impact on the subsequent reliability performance. The typical failure modes are "pop corn" effect and delamination.
AC Auto Clave (Pressure Pot)	The device is stored in saturated steam, at fixed and controlled conditions of pressure and temperature.	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity.
TC Temperature Cycling	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal displacement, dielectric cracking, molding compound delamination, wire-bonds failure, die-attach layer degradation.
<b>WBS</b> Wire Bond Shear	A process in which an instrument uses a chisel shaped tool to shear or push a ball or wedge/stitch bond off the bonding surface. The force required to cause this separation is recorded and is referred to as the bond shear strength. The bond shear strength of a ball bond, when correlated to the diameter of the ball bond, is an indicator of the quality of the metallurgical bond between the ball bond and the die bonding surface metallization.	This test establishes a procedure for determining the strength of the interface between a ball bond and a package bonding surface. This strength measurement is extremely important in determining the integrity of the metallurgical bond which has been formed.
<b>WBP</b> Wire Bond Pull	The apparatus for this test shall consist of suitable equipment for applying the specified stress to lead wire or terminal as required in the specified test condition. A calibrated measurement and indication of the applied stress in grams force (gf) shall be provided by equipment capable of measuring stresses.	The purpose of this test is to measure bond strengths, evaluate bond strength distributions, or determine compliance with specified bond strength requirements of the applicable acquisition document.



# **Public Products List**

Publict Products are off the shelf products. They are not dedicated to specific customers, they are available through ST Sales team, or Distributors, and visible on ST.com

*PCN Title :* Qualification of subcontractor TSHT for selected products in S016 package *PCN Reference :* AMS/21/12543

Subject : Public Products List

Dear Customer,

Please find below the Standard Public Products List impacted by the change.

ULQ2003D1013TR	ULN2003D1013TR	ULN2004D1013TR
ULQ2004D1013TR	ULN2002D1013TR	ULN2001D1013TR

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